

File Number 1042

T2320, T2322, T2323, T2327 Series

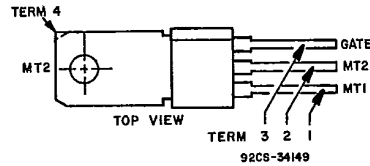
2.5-A Sensitive-Gate Silicon Triacs

For AC Power Switching

Features:

- 800V, 125 Deg. C T_J Operating
- High dv/dt and di/dt Capability
- Low Switching Losses
- High Pulse Current Capability
- Low Forward and Reverse Leakage
- Sipos Oxide Glass Multilayer Passivation System
- Advanced Unisurface Construction
- Precise Ion Implanted Diffusion Source

TERMINAL DESIGNATIONS



JEDEC TO-202AB

The RCA-T2320, T2322, T2323 and T2327, series triacs are gate-controlled full-wave silicon ac switches that are designed to switch from an off-state to an on-state for either polarity of applied voltage with positive or negative gate triggering voltages. The gate sensitivity of these triacs permits the use of economical transistorized or integrated cir-

cuit control circuits and enhances their use in low-power phase-control and load-switching applications.

All types in each series utilize the JEDEC-TO-202AB (VER-SATAB) plastic package.

MAXIMUM RATINGS, Absolute-Maximum Values:

| | 3mA Gate | T2320A | T2320B | T2320D | T2320E | T2320M | T2320N | |
|--|----------|--------|--------|------------|--------|--------|--------|------------------|
| 10 mA Gate | T2322A | T2322B | T2322D | T2322E | T2322M | T2322N | | |
| 25 mA Gate | T2323A | T2323B | T2323D | T2323E | T2323M | T2323N | | |
| 5 mA Gate | T2327A | T2327B | T2327D | T2327E | T2327M | T2327N | | |
| V_{DROM}^{Δ} (Gate Open, $T_J = -40$ to $125^{\circ}C$) | 100 | 200 | 400 | 500 | 600 | 800 | | |
| $I_{T(RMS)}$ ($T_C = 95^{\circ}C$) | | | | 2.5 | | | | A |
| $I_{T(RMS)}$ ($T_A = 25^{\circ}C$) | | | | 1 | | | | A |
| I_{TSM} (for 1 full cycle) | | | | 25 | | | | A |
| di/dt | | | | 100 | | | | A/ μs |
| I^2t [At T_C shown for $I_{T(RMS)}$] (Half-sine wave): | | | | | | | | |
| $t = 20$ ms | | | | 3.4 | | | | A ² s |
| $= 2.5$ ms | | | | 1.7 | | | | A ² s |
| $= 0.5$ ms | | | | 1 | | | | A ² s |
| For other time values | | | | See Fig. 5 | | | | |
| I_{GTM}° (For 1 μs max.) | | | | 1 | | | | A |
| P_{GM} (for 1 μs max.) | | | | 10 | | | | W |
| $P_{G(AV)}$ (Averaging time 10ms max.) | | | | 0.1 | | | | W |
| T Storage | | | | -40 to 150 | | | | $^{\circ}C$ |
| T_J | | | | -40 to 125 | | | | $^{\circ}C$ |
| T_c^{\square} : | | | | | | | | |
| During soldering for 10 s maximum at distance $\geq 1/16$ in. (1.58 mm) from seating plane | | | | 225 | | | | $^{\circ}C$ |

Δ For either polarity of main terminal 2 voltage (V_{MT2}) with reference to main terminal 1.
 \circ For either polarity of gate voltage (V_G) with reference to main terminal 1.
 \square For temperature measurement reference point, see *Dimensional Outlines*.

Triacs

T2320, T2322, T2323, T2327 Series

ELECTRICAL CHARACTERISTICS

At Maximum Ratings Unless Otherwise Specified, and at Indicated Case Temperature (T_C)

| CHARACTERISTIC | LIMITS | | | UNITS |
|--|-----------------------------------|--------|------------|--------------|
| | For All Types Except as Specified | | | |
| | Min. | Typ. | Max. | |
| $I_{DROM} \blacktriangle$: Gate open, $T_J = 125^\circ C$, $V_{DROM} = \text{Max. rated value}$ | — | 0.2 | 0.75 | mA |
| $V_{TM} \blacktriangle$: $i_T = 10 \text{ A (peak)}$, $T_C = 25^\circ C$ T2322, T2322, T2327 series $i_T = 10 \text{ A (peak)}$, $T_C = 25^\circ C$ T2323 series | — | 1.7 | 2.2 2.6 | V |
| $I_{HO} \blacktriangle$: Gate open, Initial principal current = 150 mA (dc), $V_D = 12 \text{ V}$, $T_C = 25^\circ C$ | — | 15 | 30 | mA |
| dv/dt (Commutating) \blacktriangle : $V_D = V_{DROM}$, $I_{T(RMS)} = 2.5 \text{ A}$, commutating $di/dt = 1.33 \text{ A/ms}$, gate unenergized, $T_C = 95^\circ C$ | 1 | 4 | — | V/ μs |
| dv/dt (Off-state) \blacktriangle : $V_D = V_{DROM}$, exponential voltage rise, gate open, $T_C = 125^\circ C$ | 10 | 100 | — | |
| $I_{GT} \blacktriangle \bullet$: $V_D = 12 \text{ V dc}$, $R_L = 30 \Omega$, $T_C = 25^\circ C$ (See Fig. 7) | | | | mA |
| Mode V_{MT2} V_G | | | | |
| I+ positive positive | — | — | 3 | |
| T2320 series | — | — | 10 | |
| T2322 series | — | — | 25 | |
| T2323 series | — | — | 5 | |
| T2327 series | — | — | 5 | |
| III- negative negative | — | — | 3 | |
| T2320 series | — | — | 10 | |
| T2322 series | — | — | 25 | |
| T2323 series | — | — | 5 | |
| T2327 series | — | — | 5 | |
| I- positive negative | — | — | 3 | |
| T2320 series | — | — | 10 | |
| T2322 series | — | — | 40 | |
| T2323 series | — | — | 5 | |
| T2327 series | — | — | 5 | |
| III+ negative positive | — | — | 3 | |
| T2320 series | — | — | 10 | |
| T2322 series | — | — | 40 | |
| T2323 series | — | — | 5 | |
| T2327 series | — | — | 5 | |
| $V_{GT} \blacktriangle \bullet$: $V_D = 12 \text{ V dc}$, $R_L = 30 \Omega$, $T_C = 25^\circ C$ (See Fig. 8) $V_D = V_{DROM}$, $R_L = 125 \Omega$, $T_C = 125^\circ C$ | — 0.15 | 1 — | 2.2 — | V |
| t_{gt} : $V_D = V_{DROM}$, $I_G = 60 \text{ mA}$, $t_r = 0.1 \mu s$, $i_T = 10 \text{ A (peak)}$, $T_C = 25^\circ C$ | — | 1.8 | 2.5 | μs |
| $R_{\theta JC}$ $R_{\theta JA}$ | — — | — — | 8 80 | $^\circ C/W$ |

\blacktriangle For either polarity of main terminal 2 voltage (V_{MT2}) with reference to main terminal 1.
 \bullet For either polarity of gate voltage (V_G) with reference to main terminal 1.

T2320, T2322, T2323, T2327 Series

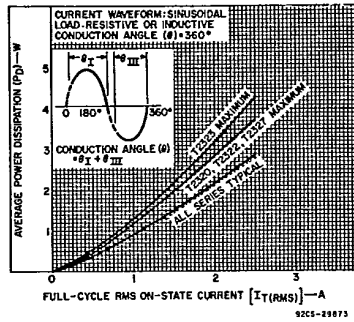


Fig. 1 — Power dissipation as a function of on-state current.

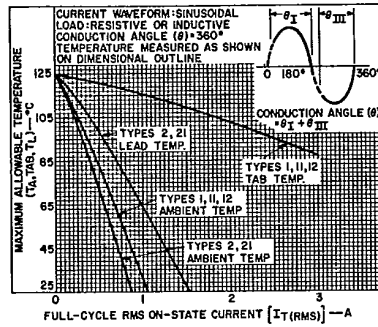


Fig. 2 — Maximum allowable temperature as a function of on-state current for T2320, T2322, and T2327.

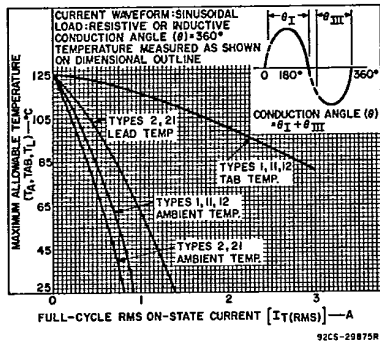


Fig. 3 — Maximum allowable temperature as a function of on-state current for T2323.

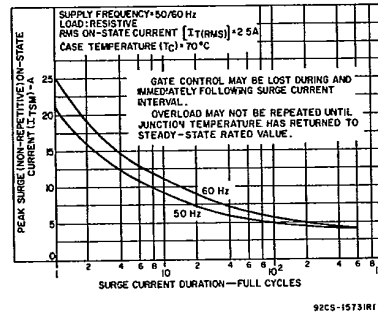


Fig. 4 — Peak surge on-state current as a function of surge-current duration.

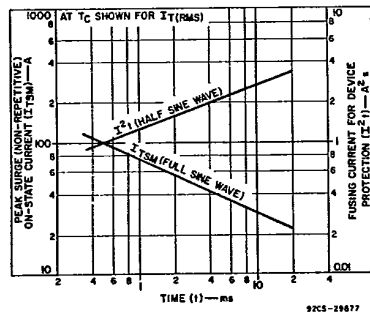


Fig. 5 — Peak surge on-state current and fusing current as a function of time.

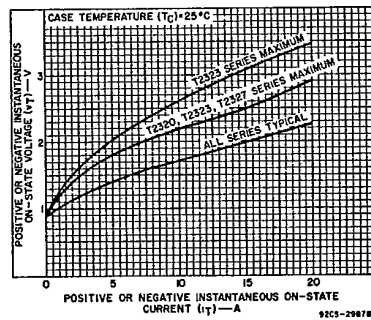


Fig. 6 — On-state current vs. on-state voltage.

Triacs

T2320, T2322, T2323, T2327 Series

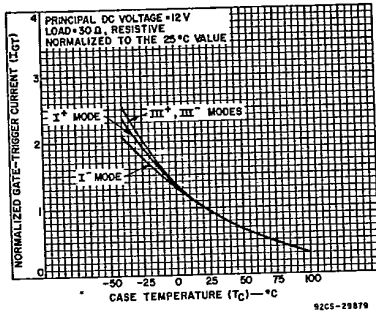


Fig. 7 — Gate-trigger current vs. case temperature.

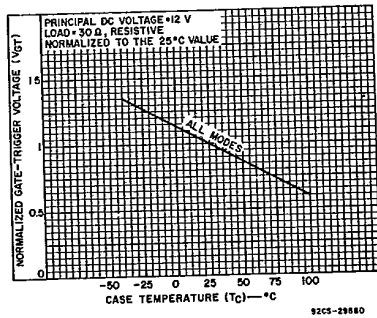


Fig. 8 — Gate-trigger voltage vs. case temperature.

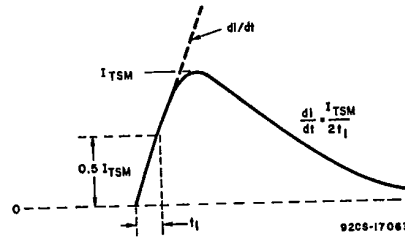
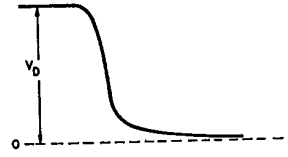


Fig. 9 — Rate-of-change of on-state current with time (defining di/dt).

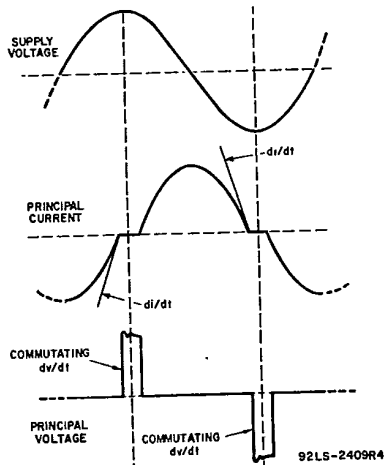


Fig. 10 — Relationship between supply voltage and principal current (inductive load) showing reference points for definition of commutating voltage (dv/dt).

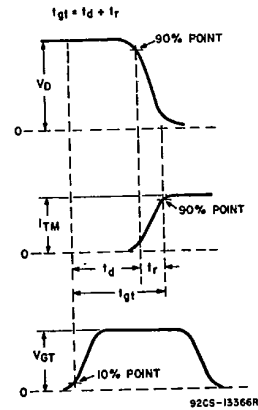


Fig. 11 — Relationship between off-state voltage, on-state current, and gate-trigger voltage showing reference points for definition of turn-on time (tgt).